

# Small Signal Switching Diodes

**Comchip**  
SMD Diode Specialist

## CDSV6-99SD-G

Reverse Voltage: 75 Volts

Forward Current: 150 mA

RoHS Device

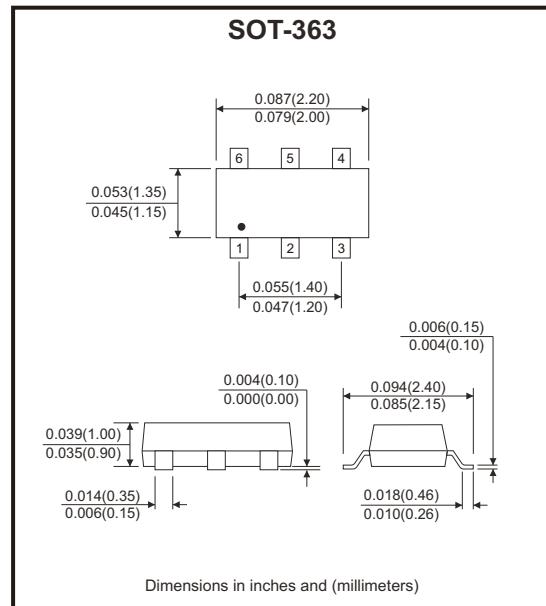


## Features

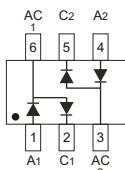
- Fast switching speed.
- Ultra small surface mount package.
- For general purpose switching applications.
- High Conductance.

## Mechanical data

- Case: SOT-363, molded plastic.
- Terminals: Solderable per MIL-STD-750, method 2026.
- Weight: 0.006 grams approx.



## Circuit Diagram



## Maximum Ratings (at Ta=25°C unless otherwise noted)

Parameter	Symbol	Limits	Unit
Peak repetitive peak reverse voltage	V <sub>RRM</sub>		
Working peak reverse voltage	V <sub>RWM</sub>	75	V
DC blocking voltage	V <sub>R</sub>		
Forward continuous current	I <sub>FM</sub>	300	mA
Average rectified output current	I <sub>O</sub>	150	mA
Non-repetitive peak forward surge current @ t=8.3ms	I <sub>FSM</sub>	2	A
Power dissipation	P <sub>D</sub>	200	mW
Thermal resistance junction to ambient	R <sub>θJA</sub>	625	°C/W
Operation junction temperature	T <sub>J</sub>	150	°C
Storage temperature range	T <sub>STG</sub>	-55 ~ +150	°C

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## Electrical Characteristics (at $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Reverse breakdown voltage	$V_{(\text{BR})}$	$I_R=2.5\mu\text{A}$	75			V
Reverse current	$I_R$	$V_R=75\text{V}$			2.5	$\mu\text{A}$
		$V_R=20\text{V}$			25	nA
Forward voltage	$V_F$	$I_F=1\text{mA}$ $I_F=10\text{mA}$ $I_F=50\text{mA}$ $I_F=150\text{mA}$			0.715 0.855 1 1.25	V
Total capacitance	$C_{\text{tot}}$	$V_R=0\text{V}, f=1\text{MHz}$			2	pF
Reverse recovery time	$t_{rr}$	$I_F=I_R=10\text{mA}, I_{rr}=0.1\times I_R, R_L=100\Omega$			4	ns

## Rating and Characteristic Curves (CDSV6-99SD-G)

Fig.1 - Forward Characteristics

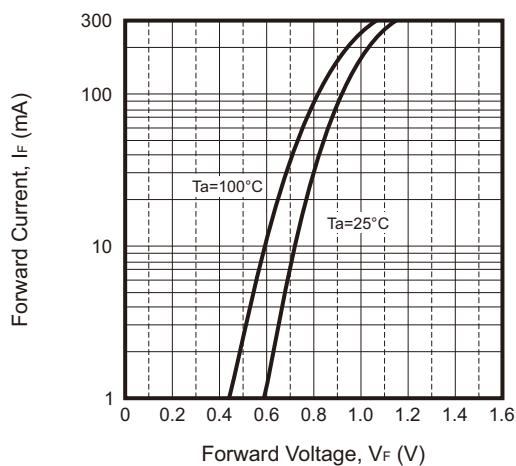


Fig.2 - Reverse Characteristics

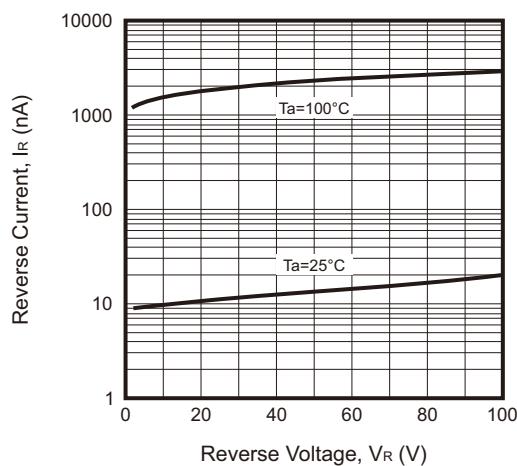


Fig.3 - Capacitance Characteristics

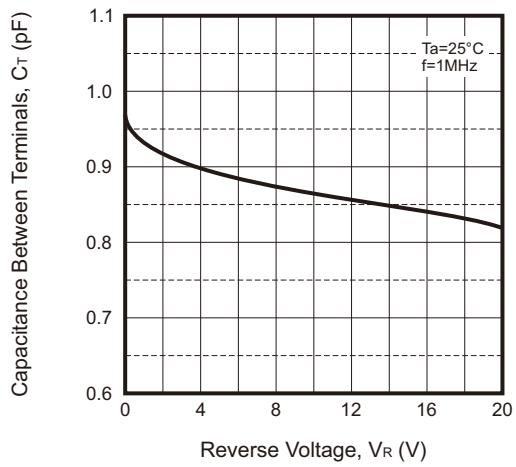
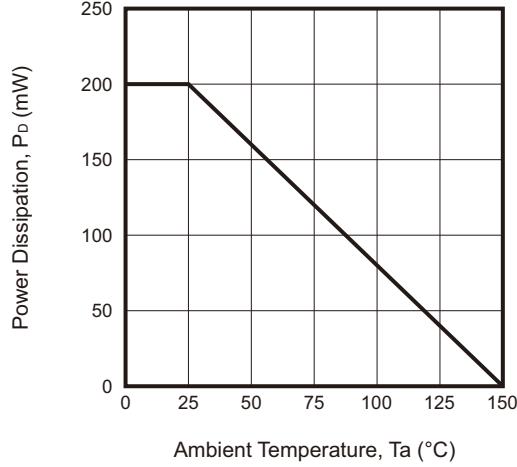


Fig.4 - Power Derating Curve



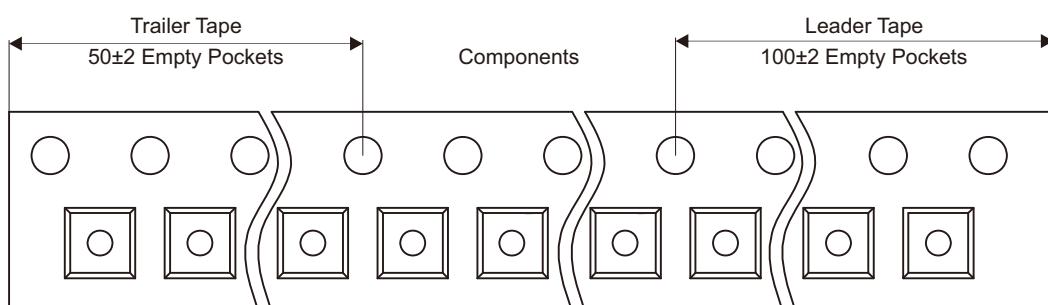
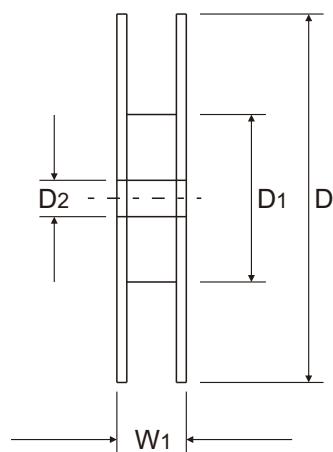
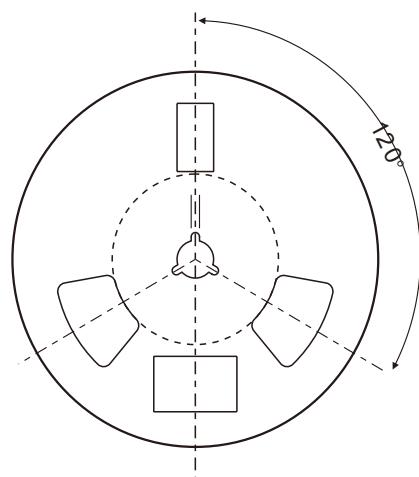
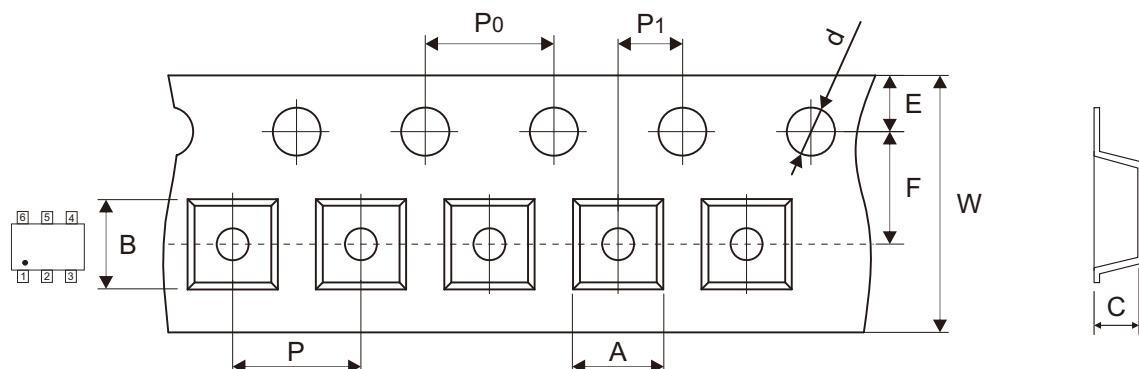
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## Reel Taping Specification



	SYMBOL	A	B	C	d	D	D1	D2
SOT-363	(mm)	2.25 ± 0.10	2.55 ± 0.10	1.20 ± 0.10	1.50 + 0.10 - 0.00	178.00 ± 1.00	54.40 ± 0.40	13.00 ± 0.20
	(inch)	0.089 ± 0.004	0.100 ± 0.004	0.047 ± 0.004	0.059 + 0.004 - 0.000	7.008 ± 0.039	2.142 ± 0.016	0.512 ± 0.008

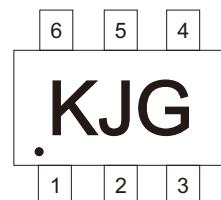
	SYMBOL	E	F	P	P0	P1	W	W1
SOT-363	(mm)	1.75 ± 0.10	3.50 ± 0.05	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	8.00 + 0.30 - 0.10	12.30 ± 1.00
	(inch)	0.069 ± 0.004	0.138 ± 0.002	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.315 + 0.012 - 0.004	0.484 ± 0.039

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## Marking Code

Part Number	Marking Code
CDSV6-99SD-G	KJG



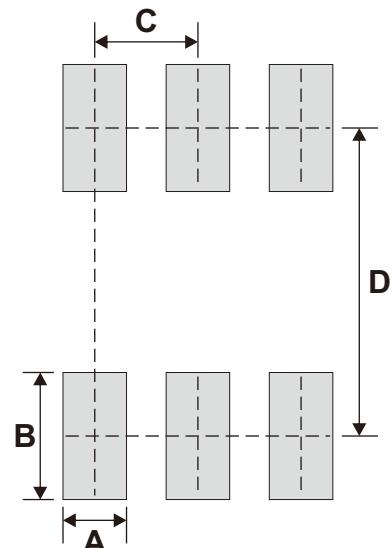
Solid dot “•” = Pin 1 indicate.

## Suggested PAD Layout

SIZE	SOT-363	
	(mm)	(inch)
A	0.40	0.016
B	0.80	0.031
C	0.65	0.026
D	1.94	0.076

Note: 1.General tolerance:  $\pm 0.05\text{mm}$ .

2.The pad layout is for reference purposes only.



## Standard Packaging

Case Type	REEL PACK	
	REEL ( pcs )	Reel Size (inch)
SOT-363	3,000	7